

DS14C232 Low Power +5V Powered TIA/EIA-232 Dual Driver/Receiver

Check for Samples: DS14C232

FEATURES

- Pin Compatible with Industry Standard MAX232, LT1081, ICL232 and TSC232
- Single +5V Power Supply
- Low Power—I_{CC} 3.0 mA Maximum
- DS14C232C Meets TIA/EIA-232-E (RS-232) and **CCITT V.28 Standards**
- **CMOS Technology**
- **Receiver Noise Filter**
- Package Efficiency—2 Drivers and 2 Receivers
- Available in Plastic DIP, Narrow and Wide **SOIC Packages**
- **TIA/EIA-232 Compatible Extended Temperature Range Option:**
 - DS14C232T -40°C to +85°C
 - DS14C232E/J: -55°C to +125°C

Connection Diagram

DESCRIPTION

The DS14C232 is a low power dual driver/receiver featuring an onboard DC to DC converter, eliminating the need for ±12V power supplies. The device only requires a +5V power supply. I_{CC} is specified at 3.0 mA maximum, making the device ideal for battery and power conscious applications. The drivers' slew rate is set internally and the receivers feature internal noise filtering, eliminating the need for external slew rate and filter capacitors. The device is designed to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE). The driver inputs and receiver outputs are TTL and CMOS compatible. DS14C232C driver outputs and receiver inputs meet TIA/EIA-232-E (RS-232) and CCITT V.28 standards.

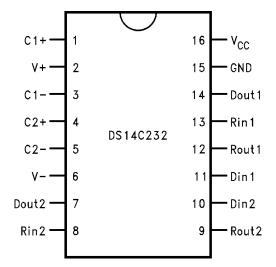


Figure 1. 16-Pin PDIP (See NFG Package)- Top View 16-Pin SOIC (See D Package)

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Functional Diagram

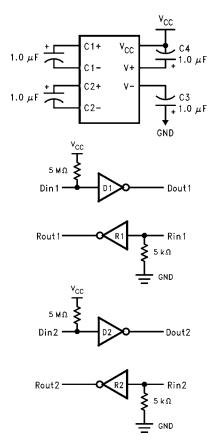


Figure 2. Functional Block Diagram



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings(1)(2)

Supply Voltage, V _{CC}	-0.3V to 6V
V ⁺ Pin	(V _{CC} - 0.3)V to +14V
V⁻ Pin	+0.3V to −14V
Driver Input Voltage	$-0.3V$ to $(V_{CC} + 0.3V)$
Driver Output Voltage	$(V^+ + 0.3V)$ to $(V^ 0.3V)$
Receiver Input Voltage	±25V
Receiver Output Voltage	$-0.3V$ to $(V_{CC} + 0.3V)$
Junction Temperature	+150°C
Maximum Package Power Dissipation @ 25°C (3)	
NFG Package	1698 mW
D Package	1156 mW
Short Circuit Duration, D _{OUT}	Continuous
Storage Temp. Range	−65°C to +150°C
Lead Temp. (Soldering, 4 sec.)	+260°C
ESD Rating	
(HBM, 1.5 kΩ, 100 pF)	≥ 2.5 kV

^{(1) &}quot;Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be verified. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

(2) Specifications for the 883 version of this product are listed separately on the following pages.

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage, V _{CC}	4.5	5.5	V
Operating Free Air Temp. (T _A)	•	•	•
DS14C232C	0	+70	°C
DS14C232T	-40	+85	°C

Electrical Characteristics⁽¹⁾

Over recommended operating conditions, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ ⁽²⁾	Max	Unit s							
DC TO D	DC TO DC CONVERTER CHARACTERISTICS												
V ⁺	Positive Power Supply	$R_L = 3 \text{ k}\Omega$, C1–C4 = 1.0 μF , $D_{\text{IN}} = 0.8 \text{V}$		9.0		٧							
V ⁻	Negative Power Supply	$R_L = 3 \text{ k}\Omega$, C1–C4 = 1.0 μF , $D_{\text{IN}} = 2.0 \text{V}$		-8.5		٧							
I _{CC}	Supply (V _{CC}) Current	No Load		1.0	3.0	mA							
DRIVER	DRIVER CHARACTERISTICS												
V _{IH}	High Level Input Voltage		2		V_{CC}	V							
V _{IL}	Low Level Input Voltage		GND		0.8	V							
I _{IH}	High Level Input Current	V _{IN} ≥ 2.0V	-10		+10	μA							
I _{IL}	Low Level Input Current	V _{IN} ≤ 0.8V	-10		+10	μA							
V _{OH}	High Level Output Voltage	$R_L = 3 \text{ k}\Omega$	5.0	8.0		V							
V _{OL}	Low Level Output Voltage	$R_L = 3 \text{ k}\Omega$		-7.0	-5.0	V							

Product Folder Links: DS14C232

⁽³⁾ Ratings apply to ambient temperature at +25°C. Above this temperature derate: NFG Package 15.6 mW/°C, and D Package 10.6 mW/°C.

⁽¹⁾ Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.

⁽²⁾ All typicals are given for $V_{CC} = 5.0V$.



Electrical Characteristics(1) (continued)

Over recommended operating conditions, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ ⁽²⁾	Max	Unit s	
I _{OS+}	Output High Short Circuit Current	$V_0 = 0V, V_{IN} = 0.8V$	See (3)	-30	-15	-5.0	mA
I _{OS} -	Output Low Short Circuit Current	$V_O = 0V$, $V_{IN} = 2V$	5.0	11	30	mA	
R _O	Output Resistance	$-2V \le V_O \le +2V$, $V_{CC} = 0V = GND$	300			Ω	
RECEIV	ER CHARACTERISTICS						
V_{TH}	Input High Threshold	V _{CC} = 5.0V		1.9	2.4	V	
	Voltage		1.9	2.6	V		
V_{TL}	Input Low Threshold Voltage		0.8	1.5		V	
V_{HY}	Hysteresis			0.2	0.4	1.0	V
R _{IN}	Input Resistance		-15V ≤ V _{IN} ≤ +15V	3.0	4.7	7.0	kΩ
I _{IN}	Input Current	V _{IN} = +15V		+2.14	+3.75	+5.0	mA
		V _{IN} = +3V		+0.43	+0.64	+1.0	mA
		V _{IN} = −3V		-1.0	-0.64	-0.43	mA
		V _{IN} = −15V		-5.0	-3.75	-2.14	mA
V _{OH}	High Level Output Voltage	$V_{IN} = -3V$, $I_O = -3.2$ mA		3.5	4.5		V
		$V_{IN} = -3V$, $I_{O} = -20 \mu A$		4.0	4.9		V
V _{OL}	Low Level Output Voltage	$V_{IN} = +3V, I_{O} = +3.2 \text{ mA}$			0.15	0.4	V

⁽³⁾ IOS₊ and IOS₋ values are for one output at a time. If more than one output is shorted simultaneously, the device power dissipation may be exceeded.

Switching Characteristics

Over recommended operating conditions, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Ma x	Units
DRIVER	CHARACTERISTICS			•			
t _{PLH}	Propagation Delay Low to High	$R_L = 3 \text{ k}\Omega$ (Figure 5, Figure 6) $C_L = 50 \text{ pF}$				4.0	μs
t _{PHL}	Propagation Delay High to Low				1.0	4.0	μs
t _{SK}	Skew t _{PLH} - t _{PHL}				0.1	1.0	μs
SR1	Output Slew Rate	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega, C_L = 50 \text{ pF}$ See ⁽¹⁾		4.0		30	V/µs
SR2	Output Slew Rate	$R_L = 3 \text{ k}\Omega, C_L = 2500 \text{ pF}$	$R_L = 3 \text{ k}\Omega, C_L = 2500 \text{ pF}$				V/µs
RECEIV	ER CHARACTERISTICS		•				
t _{PLH}	Propagation Delay Low to High	Input Pulse Width > 10 μs			2.9	6.5	μs
t _{PHL}	Propagation Delay High to Low	C _L = 50 pF		2.5	6.5	μs	
t _{SK}	Skew t _{PLH} - t _{PHL}	(Figure 7, Figure 8)				2.0	μs
t _{nw}	Noise Pulse Width Rejected	(Figure 7, Figure 8)			0.7	0.5	μs

(1) Slew rate is defined as $\Delta V/\Delta t$, measured between ±3V level.

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Absolute Maximum Ratings(1)(2)

Supply Voltage, V _{CC}	-0.3V to 6V
V ⁺ Pin	(V _{CC} - 0.3)V to +14V
V ⁻ Pin	+0.3V to −14V
Driver Input Voltage	-0.3V to (V _{CC} + 0.3V)
Driver Output Voltage	$(V^+ + 0.3V)$ to $(V^ 0.3V)$
Receiver Input Voltage	±25V
Receiver Output Voltage	-0.3V to (V _{CC} + 0.3V)
Maximum Package Power Dissipation @ 25°C (3)	
NFE Package	1520 mW
NAJ Package	2000 mW
Short Circuit Duration, D _{OUT}	Continuous
Storage Temp. Range	−65°C to +150°C
Lead Temp. (Soldering, 4 sec.)	+260°C
ESD Rating	
(HMB, 1.5 kΩ, 100 pF)	≥ 2.5 kV

[&]quot;Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be verified. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

For complete Military Product Specifications, refer to the appropriate SMD or MDS.

Recommended Operating Conditions

	Min	Max	Units				
Supply Voltage, V _{CC}	4.5	5.5	V				
Operating Free Air Temp. (T _A)							
DS14C232E/J	- 55	+125	°C				

Electrical Characteristics(1)

Over recommended operating conditions, unless otherwise specified

Symbol	Parameter	Conditions	Min	Max	Units	
DEVICE CHA	RACTERISTICS (C1-C4 = 1.0	μF)				
I _{CC}	Supply (V _{CC}) Current	No Load			8.0	mA
DRIVER CHA	RACTERISTICS					
V _{IH}	High Level Input Voltage			2		V
V _{IL}	Low Level Input Voltage				0.8	V
I _{IH}	High Level Input Current	V _{IN} ≥ 2.0V			100	μΑ
I _{IL}	Low Level Input Current	$V_{IN} = 0V$			100	μΑ
V _{OH}	High Level Output Voltage	$R_L = 3 \text{ k}\Omega$		5.0		V
V _{OL}	Low Level Output Voltage	$R_L = 3 \text{ k}\Omega$			-5.0	V
I _{OS+}	Output High Short Circuit Current	V _O = 0V	See (2)	-25		mA
I _{OS} -	Output Low Short Circuit Current	V _O = 0V			25	mA
R _O	Output Resistance	$-2V \le V_O \le +2V$, $T_A = 25$ °C, $V_{CC} = 0V = GND$		300		Ω

Ratings apply to ambient temperature at +25°C. Above this temperature derate: NFE Package 12.2 mW/°C and NAJ Package 13.3 mW/°C.

All typicals are given for $V_{CC} = 5.0V$. IOS_{+} and IOS_{-} values are for one output at a time. If more than one output is shorted simultaneously, the device power dissipation may be exceeded.



Electrical Characteristics(1) (continued)

Over recommended operating conditions, unless otherwise specified

Symbol	Parameter	Conditions	Min	Max	Units
RECEIVER (CHARACTERISTICS (C1-C4 = 1	.0 μF)			
V_{TH}	Input High Threshold Voltage			3.0	V
V _{TL}	Input Low Threshold Voltage		0.2		V
V _{HY}	Hysteresis	T _A = 25°C, +125°C	0.1	1.0	V
		T _A = −55°C	0.05	1.0	V
R _{IN}	Input Resistance	V_{IN} = ±3V and ±15V, T_A = 25°C	3.0	7.0	kΩ
V _{OH}	High Level Output Voltage	$I_{O} = -3.2 \text{ mA}$	3.5		V
		I _O = -20 μA	4.0		V
V _{OL}	Low Level Output Voltage	I _O = +3.2 mA		0.4	V

Switching Characteristics

Over recommended operating conditions, unless otherwise specified.

Symbol	Parameter	Conditions	Conditions			Units
DRIVER CI	HARACTERISTICS (C1–C4 = 1.0 μ	F)				
t _{PLH}	Propagation Delay Low to High	$R_L = 3 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	(Figure 5, Figure 6)		4.0	μs
t _{PHL}	Propagation Delay High to Low				4.0	μs
t _{SK}	Skew t _{PLH} - t _{PHL}				1.0	μs
SR1	Output Slew Rate	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega, C_L = 2500 \text{ pF}$	See (1)	1.5	30	V/µs
RECEIVER	CHARACTERISTICS (C1-C4 = 1.	0 µF)				
t _{PLH}	Propagation Delay Low to High	Input Pulse Width > 10 μs			8.0	μs
t _{PHL}	Propagation Delay High to Low	C _L = 50 pF	$C_L = 50 \text{ pF}$			
t _{SK}	Skew t _{PLH} - t _{PHL}	(Figure 7, Figure 8)			2.0	μs

(1) Slew rate is defined as $\Delta V/\Delta t$, measured between ±3V level.

Connection Diagrams

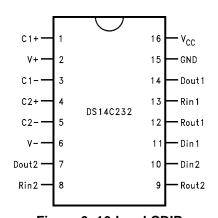


Figure 3. 16-Lead CDIP See NFE Package

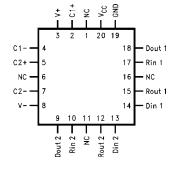


Figure 4. 20-Lead LCCC See NAJ Package

For Complete Military Product Specifications see MDS or SMD



Parameter Measurement Information

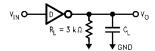


Figure 5. Driver Load Circuit

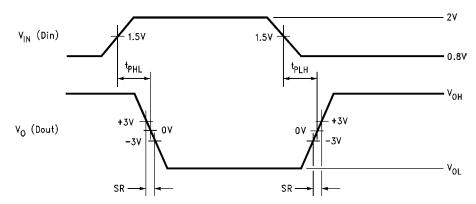


Figure 6. Driver Switching Waveform

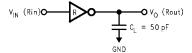
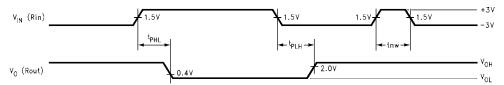


Figure 7. Receiver Load Circuit



A. Receiver AC input waveform for test purposes: tr = tf = 200 ns, VIH = 3V, VIL = -3V, f = 30 kHz.

Figure 8. Receiver Propagation Delays and Noise Rejection



PIN DESCRIPTIONS

V_{CC} (Pin 16)

Power supply pin for the device, +5V (±10%).

V+ (Pin 2)

Positive supply for TIA/EIA-232-E drivers. Recommended external capacitor: C4-1.0 μ F (6.3V). Capacitor value should be larger than 1 μ F. This supply is not intended to be loaded externally.

V- (Pin 6)

Negative supply for TIA/EIA-232-E drivers. Recommended external capacitor: C3-1.0 μ F (16V). Capacitor value should be larger than 1 μ F. This supply is not intended to be loaded externally.

C1+, C1- (Pins 1, 3)

External capacitor connection pins. Recommended capacitor: 1.0 µF (6.3V). Capacitor value should be larger than 1 µF.

C2+, C2- (Pins 4, 5)

External capacitor connection pins. Recommended capacitor: 1.0 µF (16V). Capacitor value should be greater than 1 µF.

D_{IN}1, D_{IN}2 (Pins 11, 10)

Driver input pins are TTL/CMOS compatible. Inputs of unused drivers may be left open, an internal active pull-up resistor (500 k Ω minimum, typically 5 M Ω) pulls input HIGH. Output will be LOW for open inputs.

D_{OUT}1, D_{OUT}2 (Pins 14, 7)

Driver output pins conform to TIA/EIA-232-E levels.

R_{IN}1, R_{IN}2 (Pins 13, 8)

Receiver input pins accept TIA/EIA-232-E input voltages (\pm 25V). Receivers feature a noise filter and specified hysteresis of 100 mV. Unused receiver input pins may be left open. Internal input resistor 4.7 k Ω pulls input low, providing a failsafe high output.

R_{OUT}1, R_{OUT}2 (Pins 12, 9)

Receiver output pins are TTL/CMOS compatible. Receiver output HIGH voltage is specified for both CMOS and TTL load conditions.

GND (Pin 15)

Ground Pin.

Submit Documentation Feedback



TYPICAL APPLICATION INFORMATION

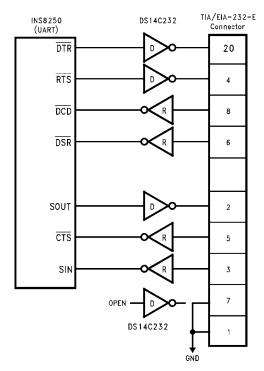


Figure 9. Application of DS14C232 and INS8250

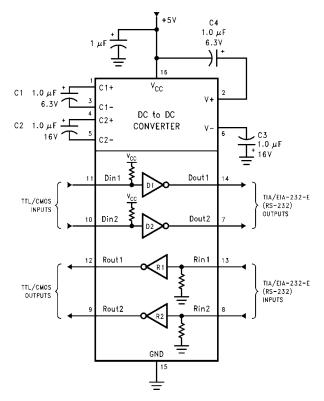
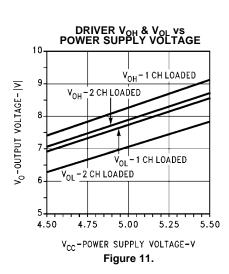


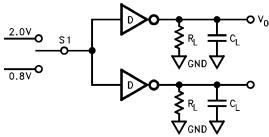
Figure 10. Typical Connection Diagram

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Typical Performance Characteristics





 $V_{CC}=5.0V,~R_L=3~k\Omega,~C_L=15~pF$ (includes jig and probe capacitance), $C_P=1~\mu F$

Figure 13.

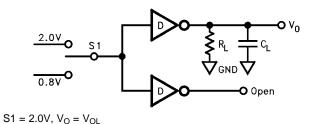


Figure 15.

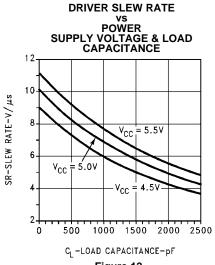
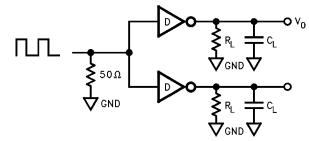


Figure 12.



 $T_a = 25$ °C, $R_L = 5$ k Ω , $C_P = 1$ μ F, f = 30 KHz

Figure 14.

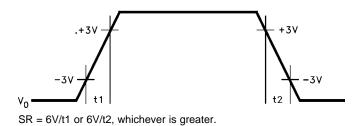


Figure 16.





REVISION HISTORY

CI	Changes from Revision B (April 2013) to Revision C							
•	Changed layout of National Data Sheet to TI format	10						





5-Oct-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
DS14C232CM	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	DS14C232CM	
DS14C232CM/NOPB	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	DS14C232CM	
DS14C232CMX/NOPB	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	DS14C232CM	
DS14C232CN/NOPB	OBSOLETE	PDIP	NFG	16		TBD	Call TI	Call TI	0 to 70	DS14C232CN	
DS14C232TM	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	DS14C232TM	
DS14C232TM/NOPB	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	DS14C232TM	
DS14C232TMX	NRND	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	DS14C232TM	
DS14C232TMX/NOPB	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	DS14C232TM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

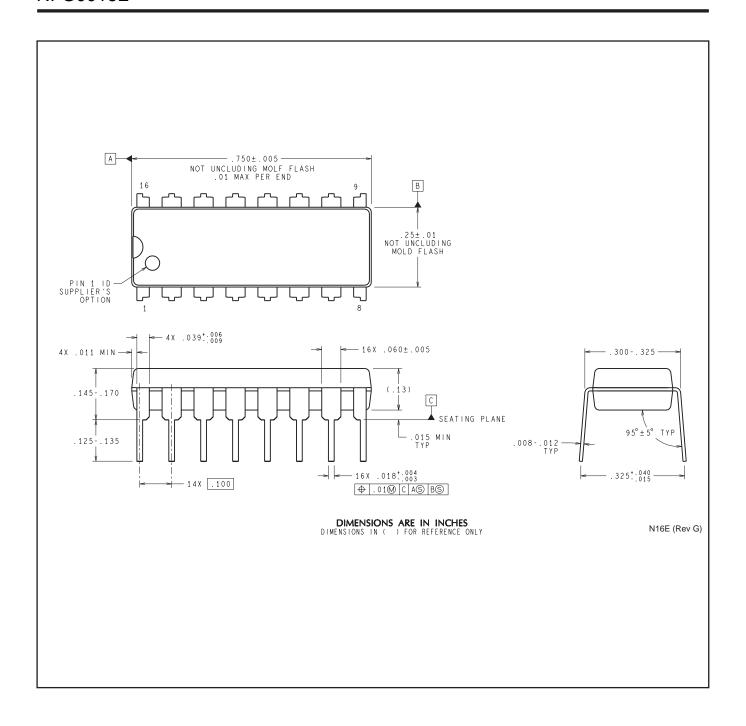


PACKAGE OPTION ADDENDUM

5-Oct-2016

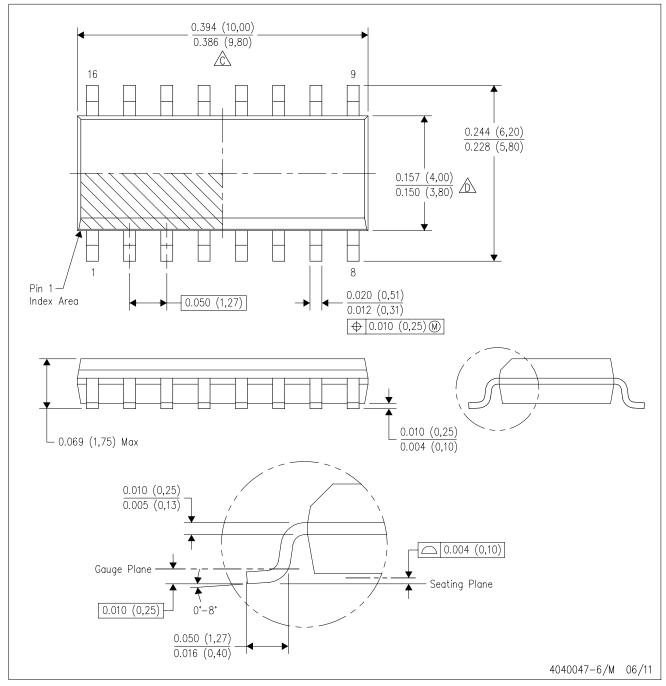
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D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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